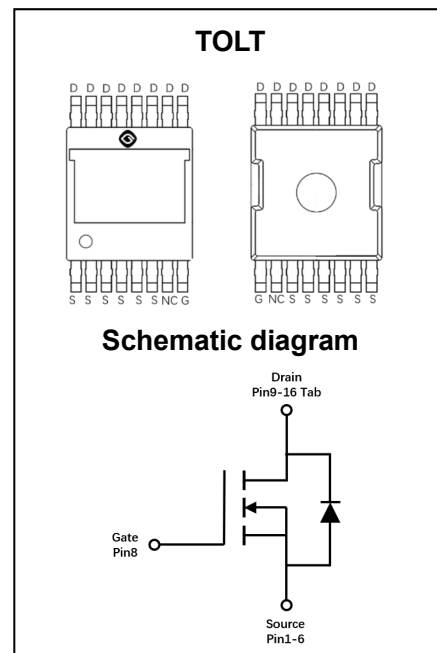




V_{(BR)DSS}	R_{DS(on)TYP}	I_D
100V	1.2mΩ@10V	410A

- Split Gate Trench Technology
- Low $R_{DS(ON)}$
- Low Gate Charge
- Low Gate Resistance
- 100% UIS Tested

- Power Switching Application
- Motor Driving



Part Number	Package	Marking	Packing	Reel Size	Tape Width	Qty
GPT013N10NTS	TOLT	T013N10N	Reel & Tape	330mm	NA	1200pcs

Parameter		Symbol	Value	Unit
Drain-Source Voltage		V_{DS}	100	V
Gate-Source Voltage		V_{GS}	± 20	V
Continuous Drain Current ¹	$T_C = 25^{\circ}C$	I_D	410	A
	$T_C = 100^{\circ}C$	I_D	254	A
Pulsed Drain Current ²		I_{DM}	1640	A
Single Pulsed Avalanche Current ³		I_{AS}	95	A
Single Pulsed Avalanche Energy ³		E_{AS}	2256	mJ
Power Dissipation ⁵	$T_C = 25^{\circ}C$	P_D	500	W
Thermal Resistance from Junction to Ambient ⁶		$R_{\theta JA}$	35	$^{\circ}C/W$
Thermal Resistance from Junction to Case		$R_{\theta JC}$	0.2	$^{\circ}C/W$
Junction Temperature		T_J	150	$^{\circ}C$
Storage Temperature		T_{STG}	-55~ +150	$^{\circ}C$

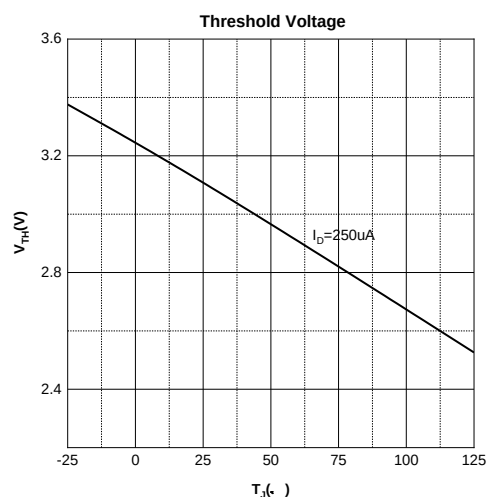
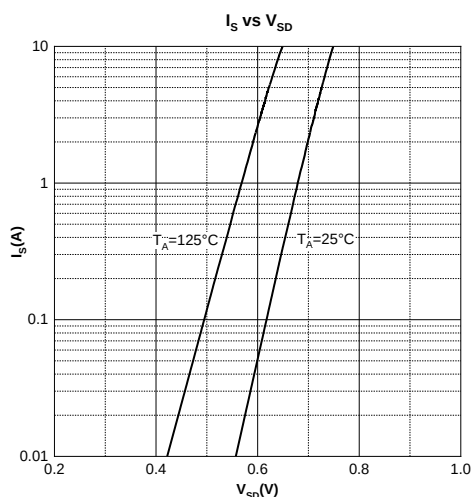
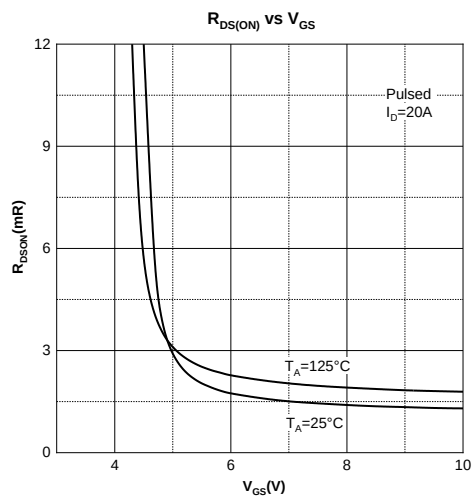
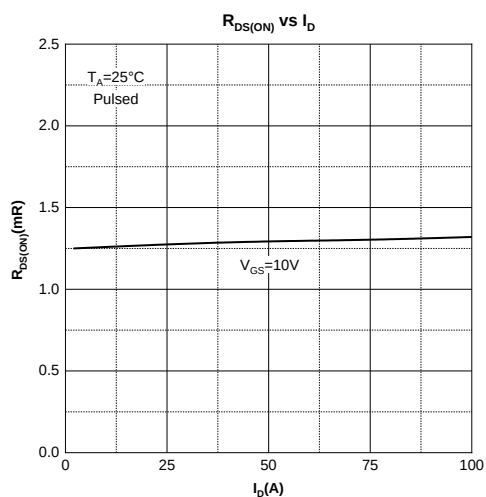
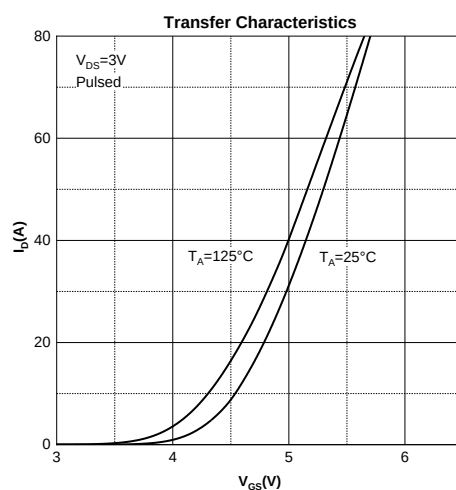
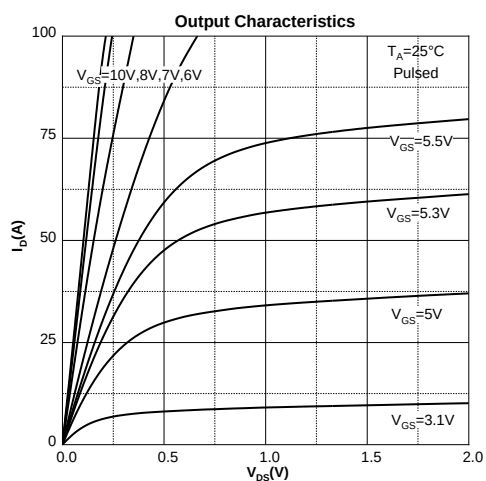
MOSFET ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

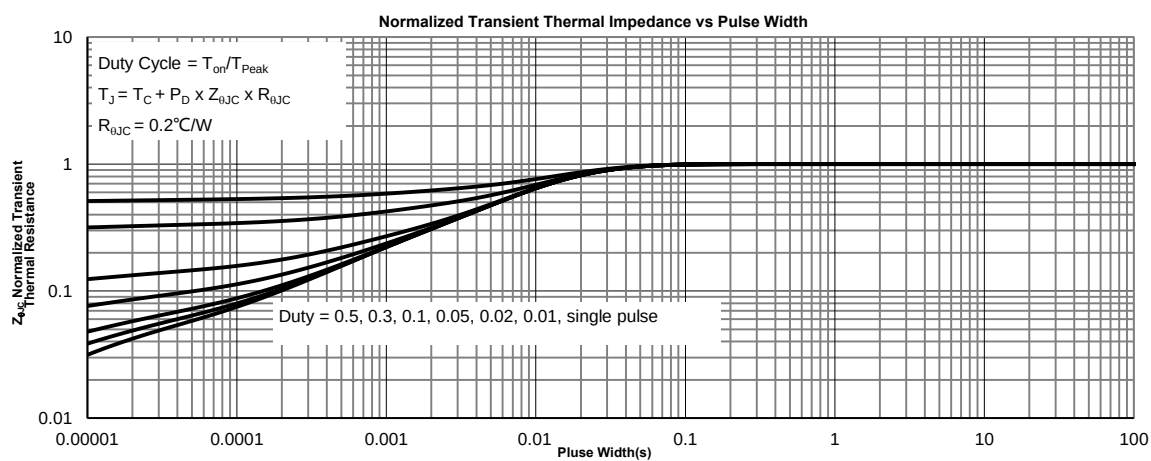
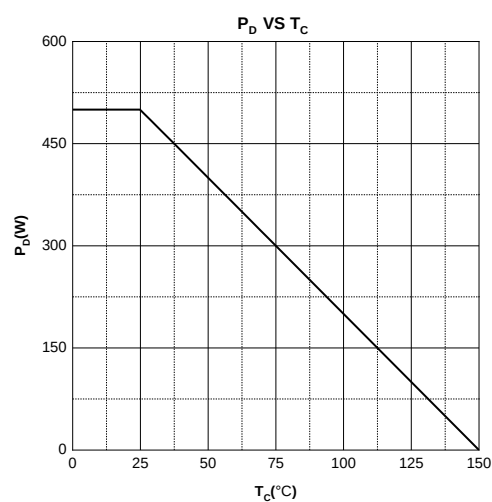
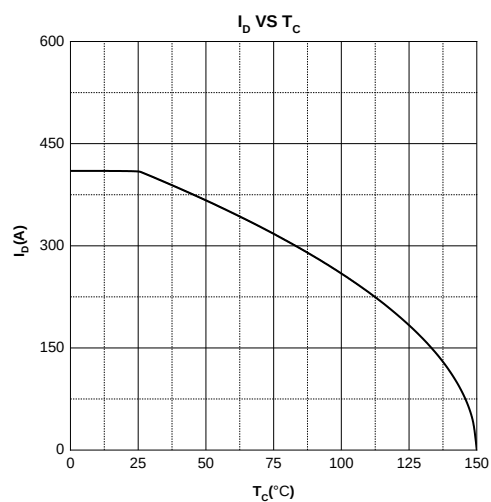
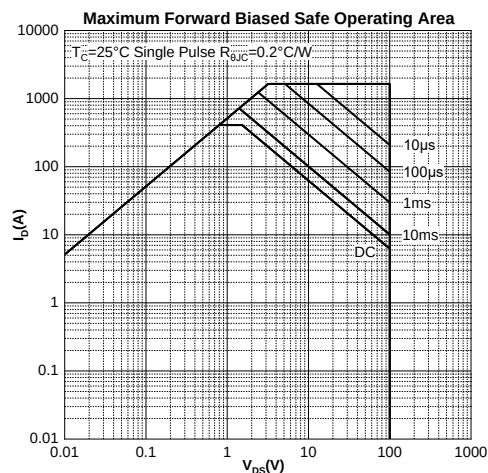
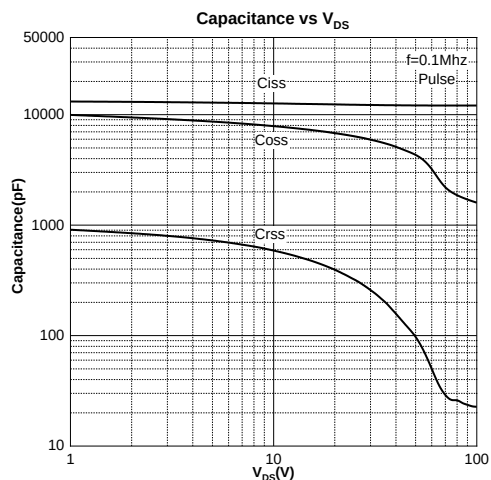
Parameter	Symbol	Test Condition	Min	Type	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS} = 0V, I_D = 250\mu A$	100			V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS} = 100V, V_{GS} = 0V$			1	μA
Gate-Body Leakage Current	I_{GSS}	$V_{GS} = \pm 20V, V_{DS} = 0V$			± 100	nA
On Characteristics ⁴						
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = 250\mu A$	2	3.1	4	V
Drain-Source On-Resistance	$R_{DS(on)}$	$V_{GS} = 10V, I_D = 20A$		1.2	1.6	m Ω
Dynamic Characteristics						
Input Capacitance	C_{iss}	$V_{DS} = 50V, V_{GS} = 0V, f = 0.1MHz$		12198		pF
Output Capacitance	C_{oss}			4312		
Reverse Transfer Capacitance	C_{rss}			95		
Gate Resistance	R_g	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$		3.1		Ω
Switching Characteristics						
Total Gate Charge	Q_g	$V_{DS} = 50V, V_{GS} = 10V, I_D = 20A$		163		nC
Gate-Source Charge	Q_{gs}			56		
Gate-Drain Charge	Q_{gd}			27		
Turn-On Delay Time	$t_{d(on)}$	$V_{DD} = 20V, V_{GS} = 10V, R_L = 1\Omega, R_G = 3\Omega$		47		ns
Turn-On Rise Time	t_r			75		
Turn-Off Delay Time	$t_{d(off)}$			116		
Turn-Off Fall Time	t_f			85		
Source-Drain Diode Characteristics						
Diode Forward Voltage ⁴	V_{SD}	$V_{GS} = 0V, I_S = 20A$			1.2	V

Notes :

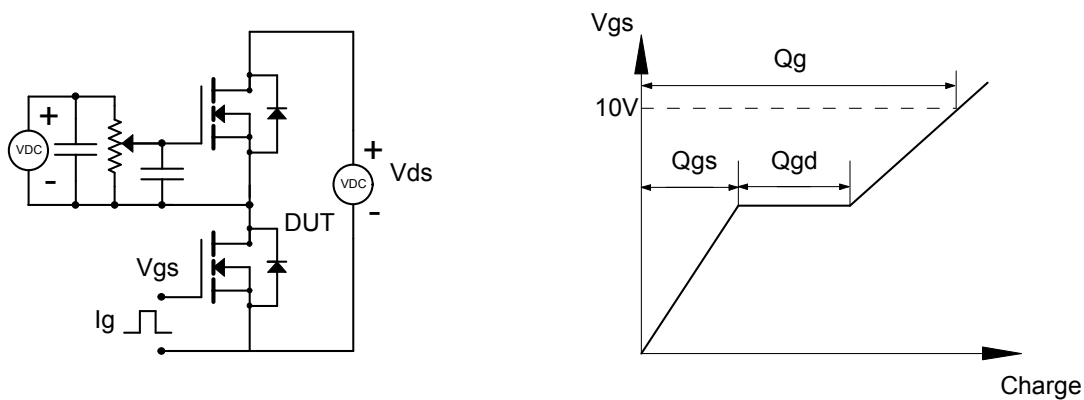
- 1.The maximum current rating is limited by package.And device mounted on a large heatsink
- 2.Pulse Test : Pulse Width $\leq 10\mu s$, duty cycle $\leq 1\%$.
- 3.EAS condition: $V_{DD} = 50V, V_{GS} = 10V, L = 0.5mH, R_G = 25\Omega$ Starting $T_J = 25^\circ\text{C}$.
- 4.Pulse Test : Pulse Width $\leq 300\mu s$, duty cycle $\leq 2\%$.
- 5.The power dissipation P_D is limited by $T_{J(MAX)} = 150^\circ\text{C}$.And device mounted on a large heatsink
- 6.Device mounted on $1in^2$ FR-4 board with 2oz. Copper, in a still air environment with $T_A = 25^\circ\text{C}$.

Typical Characteristics

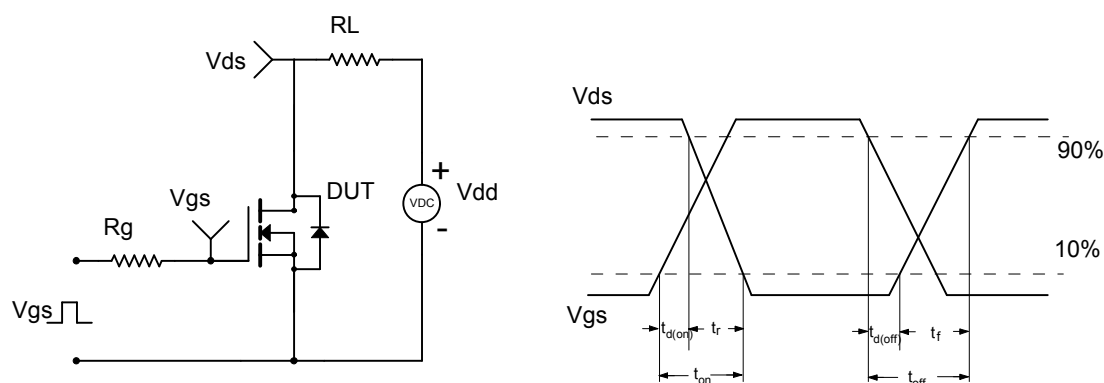




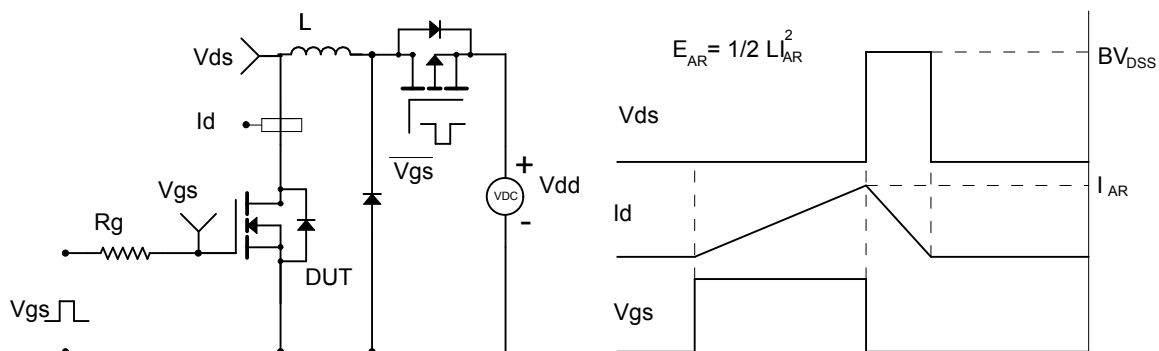
Gate Charge Test Circuit & Waveform



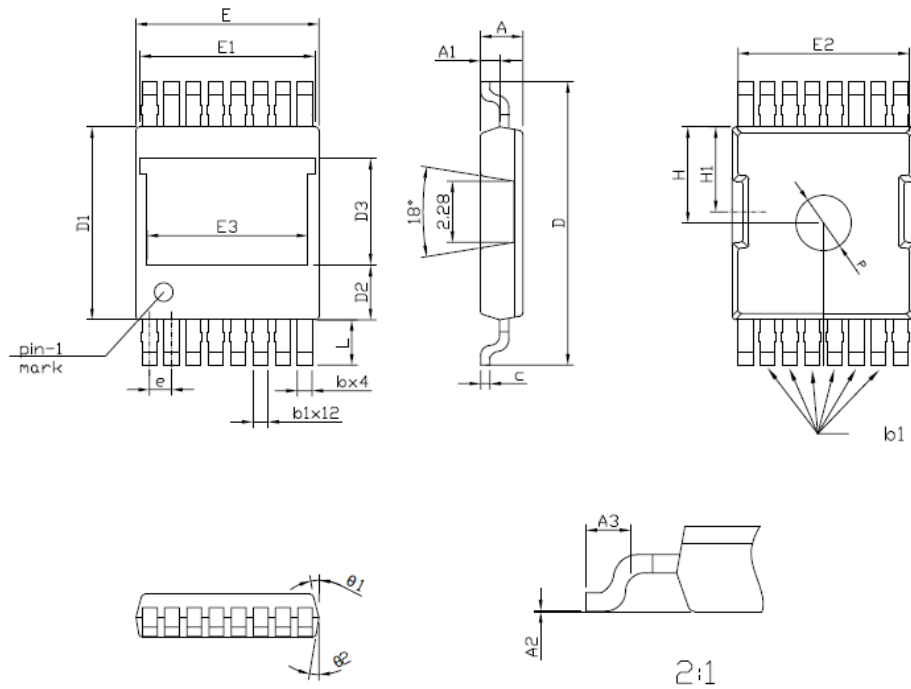
Resistive Switching Test Circuit & Waveform



Unclamped Inductive Switching (UIS) Test Circuit & Waveforms



TOLT Package Information



SYMBOL	mm		
	MIN	NOM	MAX
*A	2.25	2.30	2.35
*A1	1.00	1.04	1.08
*A2	0.01	0.08	0.16
A3	1.50REF		
*b	0.73	0.75	0.79
*b1	0.68	0.70	0.74
*c	0.45	0.50	0.55
*D	14.80	15.00	15.20
*D1	10.00	10.10	10.30
D2	2.60	2.80	3.00
D3	5.77REF		
*E	9.70	9.90	10.10
E1	9.46REF		
E2	9.25REF		
E3	8.70REF		
*e	1.18	1.20	1.22
*H	5.00	5.20	5.40
H1	4.40	4.60	4.80
*L	2.40	2.45	2.50
*P	2.80	3.00	3.20
θ1	7°	—	9°
θ2	7°	—	9°

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- GreenPower Electronics reserves the right to improve product design function and reliability without notice.
- Any and all semiconductor products have certain probability to fail or malfunction, which may result in personal injury, death or property damage. Customer are solely responsible for providing adequate safe measures when design their systems.
- GreenPower Electronics products belong to consumer electronics or other civilian electronic products.